



Capacity: 1GB - 8GB

USB 2.0 Compliant

LED activity indicator

Customizable for logo/graphic design

High Reliability:

- Guaranteed 2M Program/Erase Cycles
- Advanced Wear-Leveling
- BCH ECC Engine corrects up to 12 bits/512 Bytes errors
- Automatic Bad Block Management
- Single Level Cell (SLC) NAND Flash Memory
- 10 Year Data Retention

NEBS Level 3 compliant for ESD

8KV Contact, 15KV Air

Lot Traceability

Commercial and Extended Operating Temperature

**RoHS-6** Compliant

# SLUFDxGU2U(I)

# **General Description**

STEC's Industrial Grade USB Flash Drive (UFD) is more than just portable storage. Tailored for industrial applications that require high reliability and data throughput, it provides non-volatile, industrial grade solid-state storage in a thumb-drive package. In addition, laser-etched manufacturing information allows for lot traceability and complete info on the Bill of Materials.

The Industrial Grade UFD is available in an ESD rated enclosure (with LED light indicator) for applications that require NEBS Level 3 compliancy. The ESD-rated enclosure has been tested for immunity from ESD for 8KV contact and 15KV air.

STEC's U2, state-of-the-art, USB 2.0 flash memory controller is incorporated in the Industrial Grade UFD, providing high data integrity and endurance. The flash management software that is embedded in the controller emulates a hard disk, enabling read/write operations that are identical to a standard, sector-based hard disk. Sophisticated wear leveling algorithms ensures greater flash endurance, while automatic bad block management and a built-in ECC Engine guarantee the highest data reliability. Based on the BCH error correct algorithm, the ECC engine can correct up to 12-bit errors per 512 bytes.

High performance, high reliability and a controlled Bill-Of-Materials make the Industrial Grade UFD the product of choice in industrial applications, such as POS Workstations, Networking Equipment, automotive diagnostics and Industrial PCs.

The UFD is fully customizable to add a company logo, graphic design, or text via laser etching. In addition, STEC offers value-added services to OEM customers, such as pre-loaded content and controlled Bill Of Materials.

# **Ordering Information: USB Flash Drive**

Part Number	Capacity
SLUFD1GU2U(I)	1 GBytes
SLUFD2GU2U(I)	2 GBytes
SLUFD4GU2U(I)	4 GBytes
SLUFD8GU2U(I)	8 GBytes

#### Legend:

- SLUFD = STEC standard USB Flash Drive part number prefix.
- **G** = proceeding capacity (x) is in Gigabytes (G).
- U2 = STEC U2 controller.
- U = RoHS-6 compliant
- Part numbers without (I) = Commercial temperature range (0°C to 70°C).
- I = Extended temperature range (-15°C to 85°C).

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# 1.0 Introduction

This datasheet includes the following sections:

- *Product Specifications* covers the most referenced specifications, such as mechanical dimension, signal description, and performance.
- Theory of Operation explains the Industrial Grade UFD block diagram and flash management features.
- Environmental Specifications characterizes the recommended operating conditions, reliability parameters and shock, vibration and humidity parameters.
- *Electrical Specifications* describes the absolute maximum ratings and AC/DC characteristics.
- *Product Marking* describes the marking on the USB Flash Drive.



Figure 1: Industrial Grade USB Flash Drive



# 2.0 Product Specifications

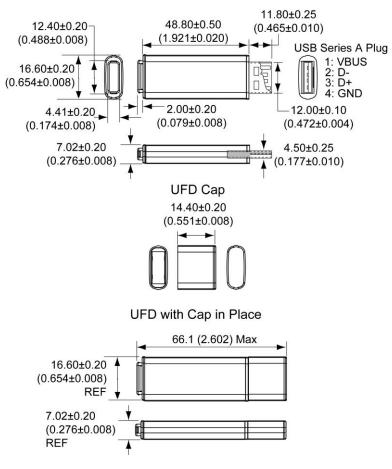
## 2.1 Mechanical Dimensions

Table 1 and Figure 2 show the mechanical dimensions of the Industrial Grade UFD with ESD-Rated Enclosure.

Table 1: Mechanical o	limension
-----------------------	-----------

Parameter	ESD-rated enclosure			
Length with Cap	66.1 mm (2.602 in) Max			
Width	16.60 ± 0.20 mm (0.654 ± 0.008 in)			
Height	7.02 ± 0.20mm (0.276 ± 0.008 in)			

Units: mm (in)



UFD with Cap Removed

Figure 2: Mechanical dimensions-UFD ESD-Rated enclosure



# 2.2 Pin Assignment and Description

Pin Number	Signal Name	Туре	Description	
1	VBUS	Power	Bus voltage supply	
2	D-	I/O	Data line –	
3	D+	I/O	Data line +	
4	GND	Ground	Ground	

Table 2: Pin Assignment and Description

# 2.3 Performance

The Industrial Grade UFD is USB 2.0 high-speed (480Mb/sec) and USB 1.1 full-speed (12Mb/sec) compliant. Measured performance for high-speed can be found in Table 3.

Table 3: Read/Write Performance

Parameter	Value
Sustained Read	up to 30 MB/sec
Sustained Write	up to 20 MB/sec

# 2.4 LED Functionality

The Industrial Grade UFD with standard enclosure incorporates a LED activity indicator that functions as described below:

- LED flashing: Industrial Grade UFD is transmitting/receiving data or is identification process
- Default LED colors: Blue



# 2.5 **Power Consumption**

The power consumption currents listed in Table 4 are for reference only. Power consumption may change according to flash memory used.

Power State	Symbol	Typ Power Consumption (1 Flash Component)	Typ Power Consumption (2 Flash Components)	Unit
Normal	I <sub>NORMAL</sub>	66.00	67.03	mA
Suspend	ISUSPEND	0.38	0.39	mA
Sleep	ISLEEP	0.38	0.38	mA
Read	I <sub>READ</sub>	91.08	104.12	mA
Write	I <sub>WRITE</sub>	93.88	118.74	mA

Table 4: Power Consumption

## Table 5: Number of Flash Components

Capacity	Number of Flash Components
1GB	2
2GB	2
4GB	2
8GB	2



# 3.0 Theory of Operation

#### 3.1 Block Diagram

The Industrial Grade UFD uses STEC's U2, state-of-the art, USB 2.0 controller, and is combined with SLC NAND Flash for optimal device reliability. The controller's firmware supports the latest NAND flash technology from multiple vendors, and is optimized for the highest performance and reliability.

The USB controller consists of the functional blocks as shown in Figure 3. The blocks are described in the paragraphs following the figure.

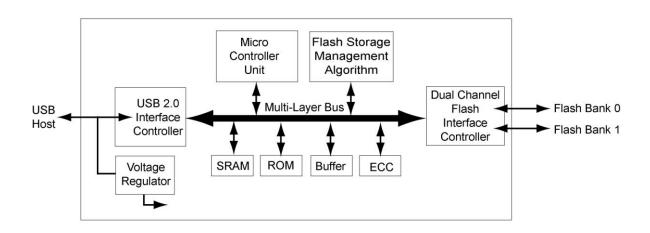


Figure 3: Controller block diagram

#### 3.1.1 Controller Internal Components

- *Microcontroller* which serves as the hardware backbone for the flash controller algorithm.
- USB 2.0 Interface Controller with high speed (480 Mbps) device function. This block interfaces with the host system via the USB interface.
- Flash Interface Controller that serves as the interface to the NAND flash components. It supports all the major NAND flash memory manufacturers.
- Flash Storage Management Algorithm Block is responsible for the flash management, including wear leveling, bad block management, and Error Correction.
- ECC block is responsible for on-the-fly error and correction.
- Sector Buffer for optimized performance.
- SRAM for running controller firmware fast and efficient.
- *ROM* for storing controllers boot code.



## 3.1.2 Controller external components

In addition to the functional blocks shown in Figure 3, the Industrial Grade UFD has the following external components:

- SLC NAND Flash for the most reliable data storage.
- Crystal Oscillator 12Mhz, as the main clock source.

#### 3.2 Flash Management

Since the Industrial Grade UFD provides a standard USB interface to the host, no software integration is required, providing the shortest time-to-market for design engineers.

The firmware of the embedded USB 2.0 controller contains STEC's advanced flash memory management algorithms to ensure the most optimum device performance, reliability and endurance. It was designed to maximize the benefits of flash memory, while at the same time overcoming inherent NAND flash limitations. Implemented in firmware are the below features:

- Flash file system management
- Bad-block management
- Wear-leveling
- Performance optimization

## 3.2.1 Bad Block Management

Inherent to NAND flash technology are areas (blocks) on the media that cannot be used for storage because of their high error rate. These so-called "bad blocks" are already identified by the flash vendor during manufacturing, but can also be accumulated over time during device operation.

The U2 controller contains a table that lists all the bad blocks on the device (Bad Block Table), and automatically maps out these blocks upon system initialization. During device operation it ensures that newly accumulated bad blocks are also mapped out and added to the Bad Block Table.

Bad block management is 100% transparent to the host application, which will not be aware of the location or existence of bad blocks on the media.



# 3.2.2 Wear Leveling

The SLC NAND flash devices that are being used in the USB Flash Drive are guaranteed for 100,000 Write/Erase cycles per block. This means that after approximately 100,000 erase cycles, the erase block has a higher probability for errors than the error rate that is typical to the flash. While 100,000 write/erase cycles may be good for consumer data storage, such as digital cameras, MP3 players, etc., it is not sufficient for industrial and embedded applications where data is constantly written to the device and long product life is required.

For example, operating systems that use a file system, will update the File Allocation Table (FAT) every time a write is done to the device. Without any wear leveling in place, the area on the flash where the FAT table is located would wear out faster than other areas, reducing the lifetime of the entire flash device.

To overcome this limitation, the flash management algorithm needs to make sure that each block in the device ages, i.e. is "worn out", at the same rate. The built-in wear leveling scheme makes sure that with every write to the flash, the youngest block is used. This ensures that the full flash media is used uniformly, so that one area of the flash will not reach the endurance limits prematurely before other areas.

# 3.2.3 Error Correction/Detection

The USB 2.0 controller implements an advanced Error Correction scheme, based on the BHC error correct algorithm. The ECC engine can correct up to 12-bits per 512 bytes (symbol based). To ensure the fastest performance, correction is done on-the-fly, in hardware only.

Each time the host application writes a sector of 512 bytes to the Industrial Grade UFD, a unique ECC signature is created by the ECC engine and written together with the data to the flash. When the data is read back by the host, the ECC engine creates again the unique ECC signature. It will then compare the original written signature with the newly created signature, and sets an error flag if the two signatures are not the same. Correction of the data is done on-the-fly when the error flag is set, and the data presented to the host will be the same as the original written data. This powerful Error Correction scheme results in an overall error rate of less than 1 in 10<sup>14</sup> bits, read.



# 3.3 OS Support

The Industrial Grade UFD is recognized as a removable drive and supports the following Operating Systems, as listed in Table 6.

Operating System	Version	
Windows 98/2000/XP/Vista		
Windows XP Embedded	Service Pack 2007	
Windows CE	4.2 and 5.0	
Windows for POS (WEPOS)		
VxWorks	6.1 and up	
Linux	Kernel 2.4 and up	

Note: Windows 98 requires driver.

#### 3.3.1 Using USB Flash Drive with XP Embedded

When using USB Flash Disk Drive with Windows XP Embedded, it is recommended that the Enhanced Write Filter (EWF) feature is implemented. The EWF intercepts calls at the sector level, and thereby eliminates many file system updates/writes to the flash. Windows XP Embedded Service Pack 2 Feature Pack 2007 introduced an additional write protect feature, called File Based Write Filter (FBWF). The new FBWF function write-protects embedded devices at the file level, in contrast to the EWF, which has been protecting devices at the sector level.

FBWF and EWF, combined with the built-in wear leveling algorithm, ensure that the maximum life span of the flash device is achieved.



# 3.4 Unique Serial Number

During manufacturing stage, a unique serial number is written to the USB Flash Disk that includes a date code related to the time of manufacturing.

The serial number uses the following format: AA[B][C][DD][EE][FFFF]. Table 7 below describes the parameters of the serial number.

Symbol	Parameter			
AA	STEC Reserved			
В	Year (hex)			
С	Month (hex)			
DD	Day (hex)			
EE	Computer Number (hex)			
FFFF	Serial Number, Incremental (hex)			

Table 7: Unique Serial Number format

The Serial Number can be obtained through Windows Device Manager or Linux Isusb utility.



# 4.0 Environmental Specifications

# 4.1 Recommended Operating Conditions

#### Table 8: Recommended Operating Conditions

Parameter	Symbol	Min	Тур	Мах	Unit
Commercial Operating Temperature	T <sub>A</sub>	0	25	70	°C
Extended Operating Temperature	T <sub>A</sub>	-15	-	85	°C
Bus Voltage (5V)	V <sub>BUS(5V)</sub>	4.75	5.0	5.25	V

# 4.2 Reliability

#### Table 9: Reliability

Parameter	Value			
Endurance	Guaranteed 2M program/erase cycles			
Data reliability	1 in 10 <sup>14</sup> bits, read			
Data retention	10 years			
Durability	1500 insertions/removals			

# 4.3 Shock, Vibration, and Humidity

Table 10: Shock, Vibration & Humidity

Parameter	Value				
Shock	1500G Peak, 0.5m pulse duration, 5 pulses, 6 axes (per JESD22-B110)				
Vibration	20G Peak, 20-2000 Hz, 4 cycles per direction (X, Y and Z) (per JESD22-B103)				
Humidity	85°C, 85% RH, Vmax for 500 hrs (per JESD22-A101)				



# 4.4 Electrostatic Discharge (ESD)

The Industrial Grade UFD has been tested for immunity from ESD under the conditions described in Table 11.

ESD Type	ESD Rated Enclosure (Maximum Discharge)
Contact	8KV
Air	15KV

Table 11: Electrostatic Discharge for UFD

## 4.5 Mean Time Between Failure (MTBF)

STEC estimates Mean Time Between Failure (MTBF), using a prediction methodology based on reliability data for the individual components in the USB Flash Drive. Table 12 summarizes the prediction results for the USB Flash Disk Drive, based on the following two methodologies:

- Telcordia Special Report SR-332, Reliability Prediction Procedure for Electronic Equipment.
- MIL-HNBK-217

The analysis was performed using Relex Software.

Product	Condition	MTBF (hours)
SLUFD4GU2U	Telcordia SR-332, GB, 25°C MIL-HNBK-217	>4,000,000
SLUFD8GU2U	Telcordia SR-332, GB, 25°C MIL-HNBK-217	>4,000,000

#### 4.6 Standards Compliance

USB Flash Drive complies with the following standards:

- CE EN 55022/55024
- FCC Class B for Information Technology
- UL 60950
- RoHS-6
- USB 2.0 Mass Storage Class



# 5.0 Electrical Specifications

## 5.1 Absolute Maximum Ratings

Operation not guaranteed at extreme corner cases.

Parameter	Symbol	Value	Unit
Power Supply Voltage Relative to Ground	V <sub>BUS</sub> -0.3 to 5.5V		V
Voltage on D+ and D- Relative to Ground	V <sub>DATA</sub> -0.3 to 3.6		V
Ambient Operating Temperature (Commercial)	T <sub>A</sub>	0 to +70	°C
Ambient Operating Temperature (Industrial)	T <sub>A</sub>	-15 to +85	°C
Storage Temperature	Tstg	-15 to +85	°C

# 5.2 DC Characteristics

Measurements at Recommended Operating Conditions, unless otherwise specified.

Table 14: DC Characteristics for Full-Speed Operation (T<sub>A</sub>=25°C, Vdd=5V, Vss=0V)

Parameter	Symbol	Test conditions	Min	Тур	Мах	Unit
Supply Voltage	V <sub>BUS</sub>		3.0	5	5.5	V
Input LOW Voltage	V <sub>IL</sub>		-	-	0.8	V
Input HIGH Voltage	VIH		2.0	-	-	V
Output LOW Voltage	V <sub>OL</sub>	R <sub>L</sub> of 1.5kΩ to 3.6V	-	-	0.3	V
Output HIGH Voltage	V <sub>OH</sub>	$R_L$ of 15k $\Omega$ to GND	2.8	-	3.6	V
Output Signal Crossover Voltage	V <sub>CRS</sub>		1.3	-	2.0	V



Parameter	Symbol	Test conditions	Min	Тур	Мах	Unit
Supply Voltage	V <sub>BUS</sub>		3.0	5	5.5	V
High Speed Idle Level	V <sub>HSOI</sub>		-10	-	10	mV
High Speed Data Signaling High	V <sub>HSOH</sub>		360	-	440	mV
High Speed Data Signaling Low	V <sub>HSOL</sub>		-10	-	10	mV
Chirp J Level (differential Voltage)	V <sub>CHIRPJ</sub>		0.7	-	1.1	V
Chirp K Level (differential Voltage)	V <sub>CHIRPK</sub>		-0.9	-	-0.5	mV

#### Table 15: DC Characteristics for High-Speed Operation (T<sub>A</sub>=25°C, Vdd=5V, Vss=0V)

# 5.3 AC Characteristics

Measurements at Recommended Operating Conditions, unless otherwise specified.

#### Table 16: AC Characteristics Full Speed

Parameter	Symbol	Min	Тур	Мах	Unit
Rise Time	T <sub>FR</sub>	4	-	20	ns
Fall Time	T <sub>FF</sub>	4	-	20	ns
Differential Rise and Fall Time Matching	T <sub>FRFM</sub>	90		111.11	%
Driver Output Resistance	Z <sub>DRV</sub>	28	-	44	Ω

## Table 17: AC Characteristics High Speed

Parameter	Symbol	Min	Тур	Мах	Unit
Rise Time (10%~90%)	T <sub>HSR</sub>	500	-	-	ps
Fall Time (10%~90%)	T <sub>HSF</sub>	500	-	-	ps
Driver Output Resistance	Z <sub>HSDRV</sub>	40.5	-	49.5	Ω



# 6.0 SCSI Command List

Command List	OpCode	RBC	SPC-2	SPC-3
INQUIRY	12h	$\checkmark$	$\checkmark$	$\checkmark$
MODESENSE(6)	1Ah	$\checkmark$	$\checkmark$	$\checkmark$
MODESENSE(10)	5Ah	-	$\checkmark$	$\checkmark$
PREVENT/ALLOW MEDIUM REMOVAL	1Eh	$\checkmark$	$\checkmark$	$\checkmark$
READ(10)	28h	$\checkmark$	-	-
READ CAPACITY	25h	$\checkmark$	-	-
REQUEST SENSE	03h	-	$\checkmark$	$\checkmark$
START STOP UNIT	1Bh	$\checkmark$	-	-
TEST UNIT READY	00h	$\checkmark$	$\checkmark$	$\checkmark$
WRITE(10)	2Ah	$\checkmark$	-	-
VERIFY(10)	2Fh		-	-
SYNC CACHE	35h	$\checkmark$	-	-



# 7.0 Product Marking

USB Flash Drive will be shipped with manufacturing info laser etched onto the device, thereby providing the option for lot traceability and full access to the Bill of Material. Figure 4 shows the product marking for the enclosure of the UFD.



Figure 4: UFD Product Marking

The front side of the USB Flash Drive shows the BOM Assembly Number; the back side shows standards logos for which the UFD was certified. Table 19 lists in detail what info can be obtained from the manufacturing information that is laser etched into the device.

BOM Assembly Number 94000-ppppp-nnnTP	Description	
94000*	STEC designation for OEM Flash products	
qqqqq	PCB number	
nnn	Capacity designator	

**Note:** If custom P/N was set up, then 94000 will be replaced with custom BOM Assembly Number designator.

# 7.1 Custom Product Marking

STEC provides the option to mark the device with a company logo, graphic design, or text via laser etching.



# 8.0 Programmed Vendor and Product Names

The USB Flash Drive can be manufactured with standard or customer-specific Vendor and Product Names. Table 20 lists the STEC standard names for USB Flash Drive.

The names can be displayed by the OS, for example, Windows XP displays the names in the notifications area in the right corner of the screen the first time the module is installed. Windows Device Manager and the properties of the USB Flash Disk Module also can display the names

Parameter	Value	
Vendor Name	"STEC"	
Product Name	"STEC USB 2.0"	

## Table 20: STEC Standard USB Vendor and Product Names



# 9.0 Contact Information

# 9.1 STEC Worldwide Headquarters

STEC INC		
3001 Daimler Street	General Support:	1-949-476-1180
Santa Ana, California 92705	Fax Number:	1-949-476-1209
United States of America (USA)	E-mail:	oemsupport@stec-inc.com

# 9.2 STEC Worldwide Locations

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	Fax: +86 21 6335 1336		



# **10.0 Revision History**

Revision	Date	Description
-101	10/24/2008	Preliminary initial release.
-102	12/03/2008	ECC Engine corrects 12 bits/512 bytes.
-103	12/09/2008	Length updated from 56.5mm to 64.5mm.
-104	12/12/2008	Endurance added to Features and Reliability table.
-105	12/22/2008	Serial Number definition updated. Bus Voltage corrected. Absolute Maximum Ratings at extreme corners or not guaranteed. Product Name programmed into device updated. Preliminary notice removed.
-106	01/09/2009	V <sub>BUS(3V3)</sub> removed from Recommended Operating Conditions.
-107	01/30/2009	Typo in Features, capacity corrected.
-108	02/06/2009	$V_{BUS(5V)}$ tolerance updated to 5%.
-109	02/23/2009	Linux utility to obtain Serial Number is corrected to Isusb.
-110	03/04/2009	Dimension illustration revised with tolerances.
-111	12/16/2009	Contact Information updated.
-112	01/22/2010	Decimal point error in body tolerance (Mechanical Dimenstions) corrected.
-113	01/28/2010	Extended Temperature added.
-114	01/29/2010	Missing dimension of USB connector added.



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61000-05387-114, January 2010